Yota Takamura

List of Publications by Year in descending order

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1040056 713466 25 415 9 21 citations h-index g-index papers 25 25 25 532 all docs docs citations times ranked citing authors

#	Article	IF	CITATIONS
1	Large Enhancement of Critical Current in Superconducting Devices by Gate Voltage. Nano Letters, 2021, 21, 216-221.	9.1	21
2	Spin–orbit torque magnetization switching in a perpendicularly magnetized full Heusler alloy Co2FeSi. AIP Advances, 2021, 11, .	1.3	1
3	Switchable Josephson junction based on interfacial exchange field. Applied Physics Letters, 2019, 114, 022601.	3 . 3	9
4	Methods to induce perpendicular magnetic anisotropy in full-Heusler Co2FeSi thin layers in a magnetic tunnel junction structure. AIP Advances, 2018 , 8 , .	1.3	9
5	Probe of spin dynamics in superconducting NbN thin films via spin pumping. Physical Review B, 2018, 97,	3.2	49
6	Inverse-magnetostriction-induced switching current reduction of STT-MTJs and its application for low-voltage MRAM. Solid-State Electronics, 2017, 128, 194-199.	1.4	2
7	Manipulation of the Magnetic Properties of Co―and Feâ€Doped Layered Titanates by Alkyl Ammonium Intercalation. Advanced Materials Interfaces, 2016, 3, 1600509.	3.7	3
8	Field-Effect Spin-Transistors. , 2016, , 1243-1279.		2
9	Spin accumulation in Si channels using CoFe/MgO/Si and CoFe/AlOx/Si tunnel contacts with high quality tunnel barriers prepared by radical-oxygen annealing. Journal of Applied Physics, 2015, 117, 17B531.	2.5	3
10	Compact magnetooptical isolator with cobalt ferrite on silicon photonic circuits. Applied Physics Express, 2015, 8, 082201.	2.4	6
11	Magnetic anisotropy of [Co2MnSi/Pd]n superlattice films prepared on MgO(001), (110), and (111) substrates. Applied Physics Letters, 2015, 106, .	3 . 3	17
12	Fabrication and characterization of spin injector using a high-quality B2-ordered-Co2FeSi0.5Al0.5/MgO/Si(100) tunnel contact. Journal of Applied Physics, 2015, 117, 17D151.	2.5	2
13	Analysis and design of nonlocal spin devices with electric-field-induced spin-transport acceleration. Journal of Applied Physics, 2015, 117, 17D919.	2.5	4
14	Full-Heusler Co2FeSi alloy thin films with perpendicular magnetic anisotropy induced by MgO-interfaces. Journal of Applied Physics, 2014, 115, .	2.5	37
15	Analysis of Hanle-effect signals observed in Si-channel spin accumulation devices. Journal of Applied Physics, 2014, 115, 17C307.	2.5	8
16	Devices and Applications: Spin Transistors and Spin Logic Devices. , 2014, , 1-31.		0
17	Analysis and control of the Hanle effect in metal–oxide–semiconductor inversion channels. Journal of Applied Physics, 2012, 111, 07C323.	2.5	7
18	Fabrication of High-Quality Co2FeSi/SiO \times N y /Si(100) Tunnel Contacts Using Radical-Oxynitridation-Formed SiO \times N y Barrier for Si-Based Spin Transistors. Journal of Electronic Materials, 2012, 41, 954-958.	2.2	9

YOTA TAKAMURA

#	Article	IF	CITATIONS
19	Analysis and Design of Hanle-Effect Spin Transistors at 300 K. IEEE Magnetics Letters, 2011, 2, 3000404-3000404.	1.1	6
20	Epitaxial germanidation of full-Heusler Co2FeGe alloy thin films formed by rapid thermal annealing. Journal of Applied Physics, 2011, 109, 07B768.	2.5	9
21	Formation of Co2FeSi/SiOxNy/Si tunnel junctions for Si-based spin transistors. Journal of Applied Physics, 2010, 107, 09B104.	2.5	9
22	Quantitative analysis of atomic disorders in full-Heusler Co2FeSi alloy thin films using x-ray diffraction with Co Kα and Cu Kα sources. Journal of Applied Physics, 2010, 107, .	2.5	43
23	Analysis of L21-ordering in full-Heusler Co2FeSi alloy thin films formed by rapid thermal annealing. Journal of Applied Physics, 2009, 105, .	2.5	127
24	Formation of Si- and Ge-based Full-Heusler Alloy Thin Films using SOI and GOI Substrates for the Half-metallic Source and Drain of Spin Transistors. ECS Transactions, 2009, 16, 945-952.	0.5	7
25	Characterization of half-metallic L21-phase Co2FeSi full-Heusler alloy thin films formed by rapid thermal annealing. Journal of Applied Physics, 2008, 103, .	2.5	25